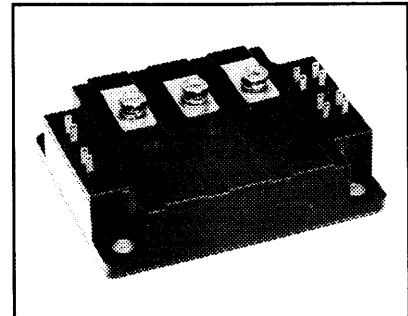
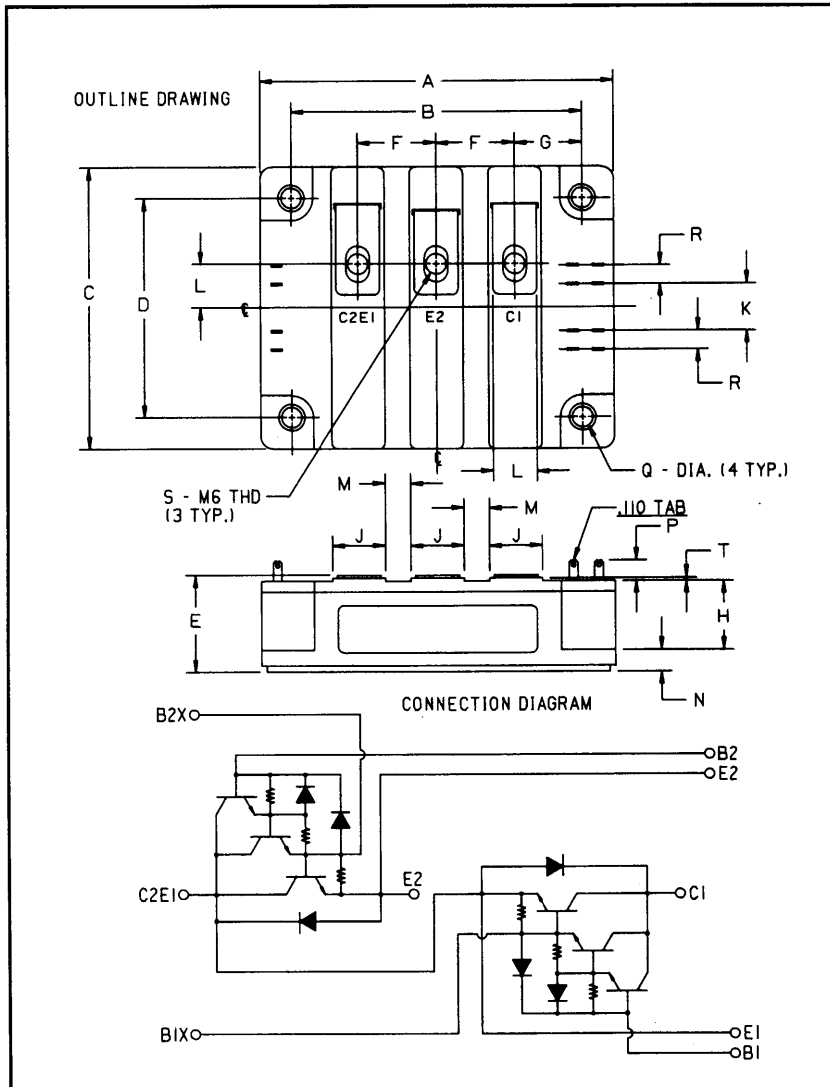


### Dual Darlington Transistor Module 200 Amperes/1000 Volts



#### Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

#### Features:

- Isolated Mounting
- Planar Chips
- Discrete Fast Recovery Feedback Diode
- High Gain ( $h_{FE}$ )
- Quick Connect Base-Emitter Signal Terminals
- Base-Emitter Speed-up Diodes

#### Applications:

- AC Motor Control
- DC Motor Control
- Switching Power Supplies
- Inverters

#### Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KD621K20 is a 1000 Volt, 200 Ampere Dual Darlington Module.

Outline Drawing

Dimensions	Inches	Millimeters
A	4.449 Max.	113 Max.
B	3.661 ± 0.012	93 ± 0.3
C	3.543 Max.	90 Max.
D	2.756 ± 0.012	70 ± 0.3
E	1.220 Max.	31 Max.
F	0.984	25
G	0.846	21.5
H	0.827	21
J	0.669	17

Dimensions	Inches	Millimeters
K	0.591	15
L	0.551	14
M	0.315	8
N	0.276	7
P	0.256 Min.	6.5 Min.
Q	0.256 dia.	6.5 Dia.
R	0.236	6
S	M6 Metric	M6
T	0.039	1

Type	$V_{CE0(sus)}$ Volts (1000)	Current Rating Amperes (X 10)
KD62	1K	20



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

**KD621K20**  
**Dual Darlington Transistor Module**  
 200 Amperes/1000 Volts

**Absolute Maximum Ratings,  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	KD621K20	Units
Junction Temperature	$T_J$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	1000	Volts
Collector-Base Voltage	$V_{CBO}$	1000	Volts
Emitter-Base Voltage	$V_{EBO}$	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	$V_{CEV}$	1000	Volts
Continuous Collector Current	$I_C$	200	Amperes
Diode Forward Current	$I_{FM}$	200	Amperes
Continuous Base Current	$I_B$	10	Amperes
Diode Surge Current	$I_{FSM}$	2000	Amperes
Power Dissipation (Each Transistor)	$P_t$	1560	Watts
Max. Mounting Torque M6 Terminal Screws	—	26	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	265	in.-lb.
Module Weight (Typical)	—	870	Grams
V Isolation	$V_{RMS}$	2500	Volts

**Electrical Characteristics,  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Collector Cutoff Current	$I_{CEV}$	$V_{CE} = 1000\text{V}, V_{BE} = -2\text{V}$	—	—	4	mA	
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 7\text{V}$	—	—	800	mA	
DC Current Gain	$h_{FE}$	$I_C = 200\text{A}, V_{CE} = 2.8\text{V}$	75	—	—	—	
		$I_C = 200\text{A}, V_{CE} = 5.0\text{V}$	100	—	—	—	
Diode Forward Voltage	$V_{FM}$	$I_{FM} = 200\text{A}$	—	—	1.8	Volts	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 200\text{A}, I_B = 4\text{A}$	—	—	2.5	Volts	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 200\text{A}, I_B = 4\text{A}$	—	—	3.5	Volts	
Resistive	Turn-on	$t_{on}$	$V_{CC} = 600\text{V}$	—	—	3.0	$\mu\text{s}$
Load	Storage Time	$t_s$	$I_C = 200\text{A}$	—	—	15	$\mu\text{s}$
Switch Times	Fall Time	$t_f$	$I_{B1} = -I_{B2} = 4\text{A}$	—	—	3.0	$\mu\text{s}$

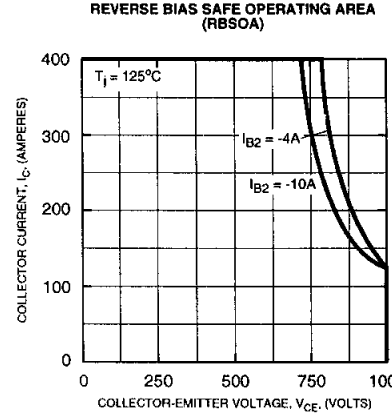
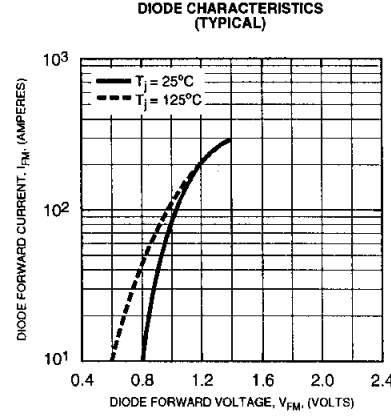
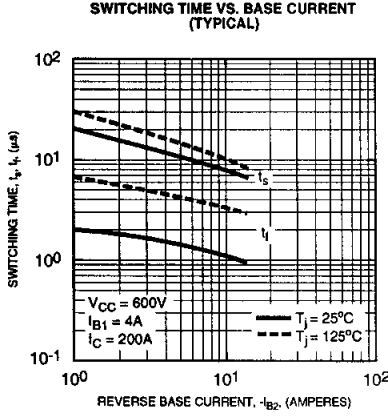
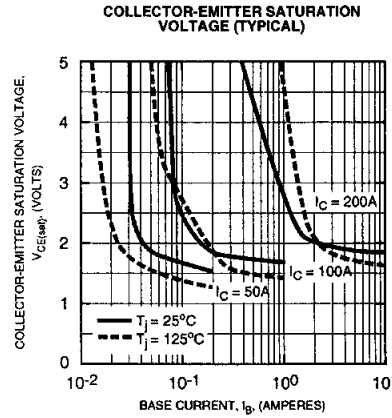
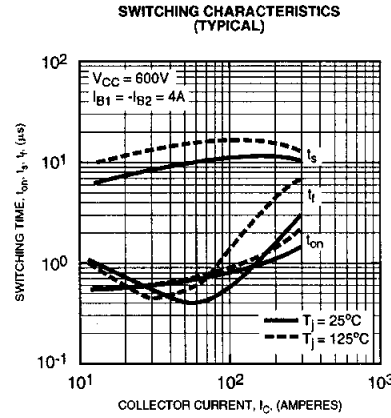
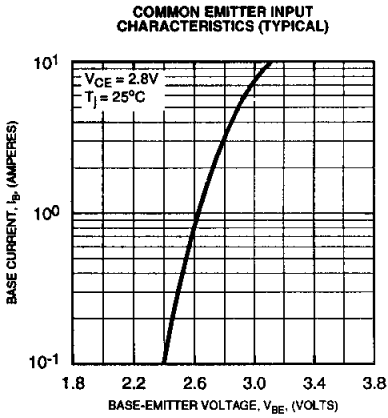
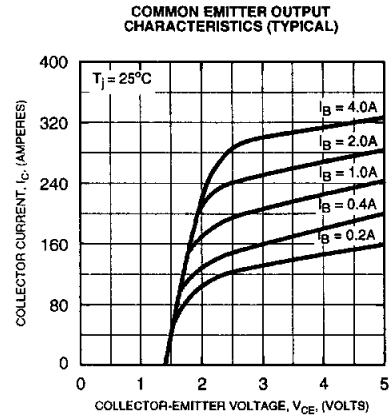
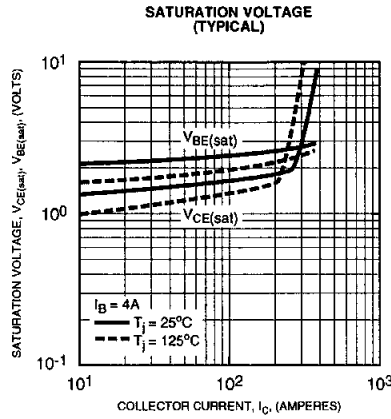
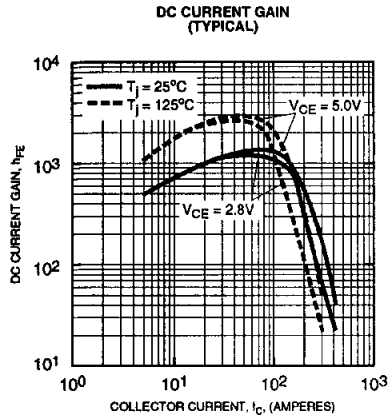
**Thermal and Mechanical Characteristics,  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	—	—	0.08	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	—	—	0.35	$^\circ\text{C/W}$



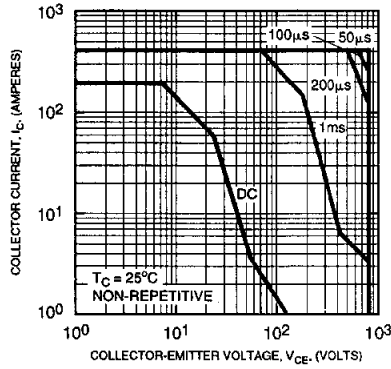
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**KD621K20**  
**Dual Darlington Transistor Module**  
**200 Amperes/1000 Volts**

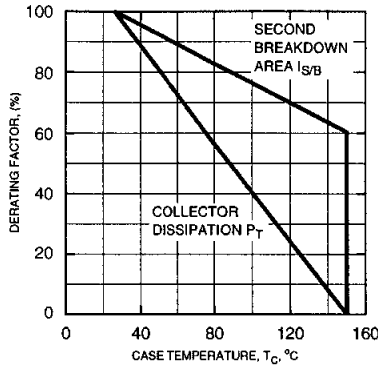


**KD621K20**  
**Dual Darlington Transistor Module**  
 200 Amperes/1000 Volts

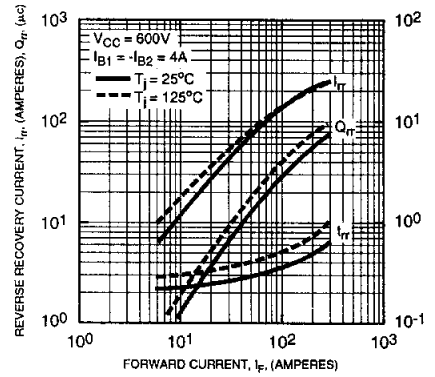
**FORWARD BIAS SAFE OPERATING AREA (SOA)**



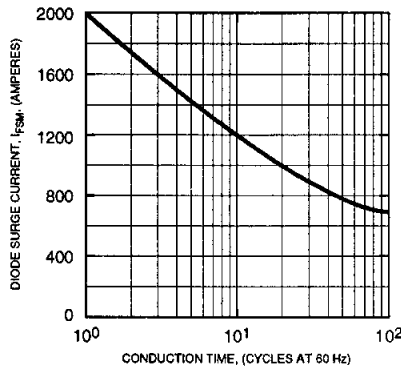
**DERATING FACTOR OF SAFE OPERATING AREA (SOA)**



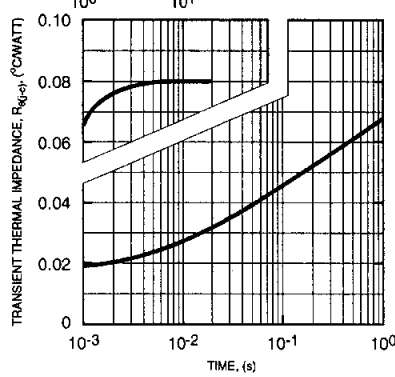
**REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)**



**DIODE FORWARD SURGE CURRENT**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (TRANSISTOR)**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (DIODE)**

